



भौतिकी संस्थान
भुवनेश्वर
Institute of Physics
Bhubaneswar - 751005, India

BY SPEED POST

(परमाणु ऊर्जा विभाग, भारत सरकार का एक स्वायत्त अनुसंधान संस्थान)
(An autonomous research institution of Dept. of Atomic Energy, Govt. of India)

QUOTATION CALL NOTICE

Ref.No. IOP/PUR/PRO-INSP/2022-23/ <u>638</u>	Rate quotation for:
Date: <u>08/07/2022</u>	Silicon Wafers 2"

To:

M/s

Dear Sir,


Sealed quotation is invited for supply of Crystalline Silicon Wafers as per specification, terms and conditions noted below.

Sl.	Description/Specification	Qty.	Price
1	Silicon Wafers; 2" size (Specification attached)	25 Nos.	

TERMS & CONDITIONS:

1. Intending supplier should be a registered dealer having GST Registration No. and should submit a copy of the same.
2. Quotation is to be submitted by **post/courier** only in sealed envelope **with superscription "Silicon Wafers 2" size"** and addressed to the Registrar, Institute of physics, P.O: Sainik School, Bhubaneswar-751005.
3. The quotation should be submitted within **15 days** from the date of issue of this letter in the office of the Registrar along with copies of the aforesaid certificates and authorization from OEM if any failing which the same will be rejected.
4. Rate quoted should remain valid for ninety days from the date of submission of the quotation.
5. Price quoted should be FOR destination at IOP site basis.
6. The items must be warranted against any functional defects.
7. Taxes & levies: As mentioned above. **The institute is eligible for exemption & to pay tax @ 5%. The Exemption Certificate issued by Department of Atomic Energy (DAE), Government of India, vide No.4416/20(2)/2009/IOP/R&D-II/2751 dated 28.02.2018 is attached for your reference.**
8. 100% payment will be made on delivery of goods in satisfactory conditions and against submission of bill/invoice in duplicate.

भवदीय/Yours faithfully


रजिस्ट्रार/ REGISTRAR

Sr. No	Part No.	Description		Qty
1		Specification	Prime FZ	25
		Diameter	2" (50.8 ± 0.3 mm)	
		Type & dop	N - Phosphorus	
		Orientation	(100) ± 0.5°	
		Off orientation		
		Resistivity	3 - 20 Ohm.cm	
		Primary flat	Semi Std	
		Secondary flat		
		Thickness	250 ± 20 µm	
		TTV	< 10 µm	
		Bow Warp	< 30 µm	
		Edge rounding	Semi Std	
		Surface	Double Side Polished	
		Laser marking	None	
		Remark	Lifetime > 1 ms	